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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/710,257	06/29/2004	Ravikumar Ramachandran	FIS920040102US1	4256	
32074 75	90 06/30/2006		EXAMINER		
INTERNATIONAL BUSINESS MACHINES CORPORATION			DUONG, KHANH B		
DEPT. 18G BLDG. 300-482		ART UNIT	PAPER NUMBER		
2070 ROUTE 5		2822			
HOPEWELL JU	JNCTION, NY 12533	DATE MAILED: 06/30/2006			

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applicati	on No.	Applicant(s)				
		10/710,2	57	RAMACHANDRAN ET AL.				
Office Action Summary		Examine	Г	Art Unit				
		Khanh B.	Duong	2822				
Period fo	The MAILING DATE of this commun or Reply	nication appears on th	e cover sheet with the c	correspondence ad	idress			
WHIC - Exter after - If NC - Failu Any	ORTENED STATUTORY PERIOD IN CHEVER IS LONGER, FROM THE IN POSITION OF THE INSTRUMENT	MAILING DATE OF TI s of 37 CFR 1.136(a). In no ex munication. statutory period will apply and w y will, by statute, cause the app	HIS COMMUNICATION vent, however, may a reply be tire vill expire SIX (6) MONTHS from plication to become ABANDONE	N. mely filed the mailing date of this c ED (35 U.S.C. § 133).				
Status								
1) 又	Responsive to communication(s) fil	ed on <i>26 May 2006</i> .						
<u> </u>	This action is FINAL .	2b)⊠ This action is r	non-final.					
,	osecution as to the	e merits is						
-,	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Dispositi	on of Claims	·						
4)⊠	Claim(s) <u>1-20</u> is/are pending in the application.							
, —	4a) Of the above claim(s) <u>11-20</u> is/are withdrawn from consideration.							
	Claim(s) is/are allowed.							
	Claim(s) is/are anowed. Claim(s) 1-10 is/are rejected.							
	Claim(s) <u>1-70</u> is/are rejected. Claim(s) is/are objected to.							
<u> </u>	Claim(s) are subject to restri	ction and/or election	requirement.					
•	on Papers		•					
	•	Eveniner			•			
·	The specification is objected to by the		\□ abjected to by the	Evaminar				
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).								
			-		ED 1 101/d)			
11)	Replacement drawing sheet(s) includin The oath or declaration is objected to							
·	ınder 35 U.S.C. § 119	o by the Examiner. W		Action of formal	0-102.			
	_	. for foreign maiority) (al) (f)				
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).								
a)	☐ All b)☐ Some * c)☐ None of:	, dagumanta haya ha	id					
	1. Certified copies of the priority documents have been received.2. Certified copies of the priority documents have been received in Application No							
					Ohama			
	3. Copies of the certified copies	•		ed in this National	Stage			
* 0	application from the Internation the application from the Internation of the application and the Internation of the Internation	·		~ d				
~ 3	See the attached detailed Office action	on for a list of the cert	ified copies not receive	ea.				
Assas	4/_}							
Attachmen	e of References Cited (PTO-892)		4) Interview Summary	/DTO 412\				
	e of Draftsperson's Patent Drawing Review(PTO-948)	Paper No(s)/Mail D	-				
3) Inform	nation Disclosure Statement(s) (PTO-1449 or No(s)/Mail Date		5) Notice of Informal F 6) Other:	Patent Application (PTC)-152)			

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DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on May 26, 2006 has been entered.

Response to Amendment

Accordingly, claims 1 and 9 were amended.

Claims 11-20 remain withdrawn from further consideration by the examiner as being drawn to a non-elected invention.

Currently, claims 1-10 remain active.

Response to Arguments

Applicant's arguments with respect to the <u>amended</u> claims have been considered but are moot in view of the new ground(s) of rejection.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

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The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

- 1. Determining the scope and contents of the prior art.
- 2. Ascertaining the differences between the prior art and the claims at issue.
- 3. Resolving the level of ordinary skill in the pertinent art.
- 4. Considering objective evidence present in the application indicating obviousness or nonobviousness.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1-10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ngo et al. (U.S. 6,545,370) in view of Jung et al. (U.S. 2005/0170104 A1).

Ngo et al. ("Ngo") discloses in FIG. 2 a method of forming a semiconductor device comprising the steps: providing a substrate 20 having at least one gate stack 21 having first and second sidewalls; depositing a silicon nitride layer by means of a dual-frequency plasma enhanced CVD process (PECVD), the PECVD process comprising a temperature in the range 380°C to 420°C; forming from said silicon nitride layer first and second separate, unconnected sidewall spacers 24, the first sidewall spacer 24 extending along at least a portion of the first

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sidewall and the second spacer 24 extending along at least a portion of the second sidewall; and forming an (N or P) FET device comprising said at least one gate stack 21 having said spacer 24.

Ngo further discloses the PECVD process comprising: a temperature in the range 380°C to 420°C; a pressure in the range of 1.6 to 2.2 Torr; a low frequency power in the range of 100 to 200 watts; a high frequency power in the range of 350 to 450 watts; and precursor gases of silane, ammonia and nitrogen at flow rates in the ratio in the range of 200-450:2,000-4,000 sccm [see col. 4, lines 35-44].

Re claims 1-10, Ngo does <u>not</u> specifically disclose the PECVD process comprising: a temperature in the range of 400°C to 550°C; a pressure in the range of 2 to 5 Torr; a low frequency power in the range of 0 to 50 watts; a high frequency power in the range of 90 to 110 watts; and precursor gases of silane, ammonia and nitrogen at flow rates in the ratio in the range of 240:3200:4000 sccm.

Jung et al. ("Jung"), previously cited, suggests a dual-frequency PECVD process comprising: a temperature in the range of 375°C to 550°C; a pressure in the range of 2 to 15 Torr; a low frequency power in the range of 0 to 100 watts; a high frequency power in the range of 10 to 200 watts; and precursor gases of silane, ammonia and nitrogen at flow rates in the ratio in the range of 40-350:1,000-5,000:2,000-20,000 sccm [see TABLES II & III; page 7, paragraph 0087 to page 8, paragraph 0095].

Since Ngo and Jung are from the same field of endeavor, the purpose disclosed by Jung would have been recognized in the pertinent prior art of Ngo.

Therefore, it would have been obvious to a person of ordinary skill in the art at the time the invention was made to optimize and select appropriate temperature, powers and flow rate Application/Control Number: 10/710,257

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ratio in the ranges as combinatively suggested by Ngo and Jung. The selection of parameters such as energy, power, concentration, temperature, time, depth, thickness, etc., would have been obvious and involve routine optimization which has been held to be within the level of ordinary skill in the art. "Normally, it is to be expected that a change in temperature, or in concentration, or in both, would be an unpatentable modification. Under some circumstances, however, changes such as these may be impart patentability to a process if the particular ranges claimed produce new and unexpected result which is different in kind and not merely degree from results of prior art ... such ranges are termed 'critical ranges' and the applicant has the burden of proving such criticality ... More particularly, where the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation". *In re Aller*, 105 USPQ 233, 235 (CCPA 1955). See also MPEP 2144.05.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Khanh B. Duong whose telephone number is (571) 272-1836. The examiner can normally be reached on 10:00-6:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Zandra Smith can be reached on (571) 272-2429. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

KBD

Supervisory Patent Examiner